

PAR2801-Q32P

Low-energy Bluetooth 5.0 Module



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1 Device Overview

1.1 Features

- Qualified Bluetooth Low Energy V5.0 slave device
- Cortex-M0 32-bit MCU with max. 32 MHz clock rate
- Low power and excellent performance 2.4 GHz transceiver
- 2 channels 10-bit SAR ADC
- 128 KB flash, 80 KB SRAM, and 24 KB ROM
- 16 MHz and 32.768 kHz crystal oscillator circuit
- Communication interfaces supported
 - Two I2C master
 - Two 2/4-wire SPI master
 - Two UART
- Digital peripherals
 - Three LED drive IO
 - Three PWM channels
- PCB antenna with 50 ohm impedance and an optional RF pin to connect to an external antenna
- 4 dBm maximum transmitting power
- -93 dBm receiving sensitivity
- No shielding cover

1.2 Applications

- HID peripherals
- Health and fitness wearable devices
- Interactive entertainment devices
- Home and industrial automation
- Security / Proximity applications

1.3 Descriptions

The PAR2801-Q32P module is a BLE module built around PixArt Cortex-M0 core BLE 5.0 SoC PAR2801 QN-GHVC chip. It integrates 128 KB on-chip flash and 80 KB SRAM. The peripherals include 18 GPIOs multiplexed with PWM, I2C, UART, ADC and SPI interfaces.

1.4 Functional Block Diagram

The PAR2801QN-GHVC chip has integrated an ARM® Cortex®-M0 processor, a BLE 4.0 baseband control core ROM, Flash, Bluetooth Modem, Radio Transceiver, on-chip Balun for the BLE application.

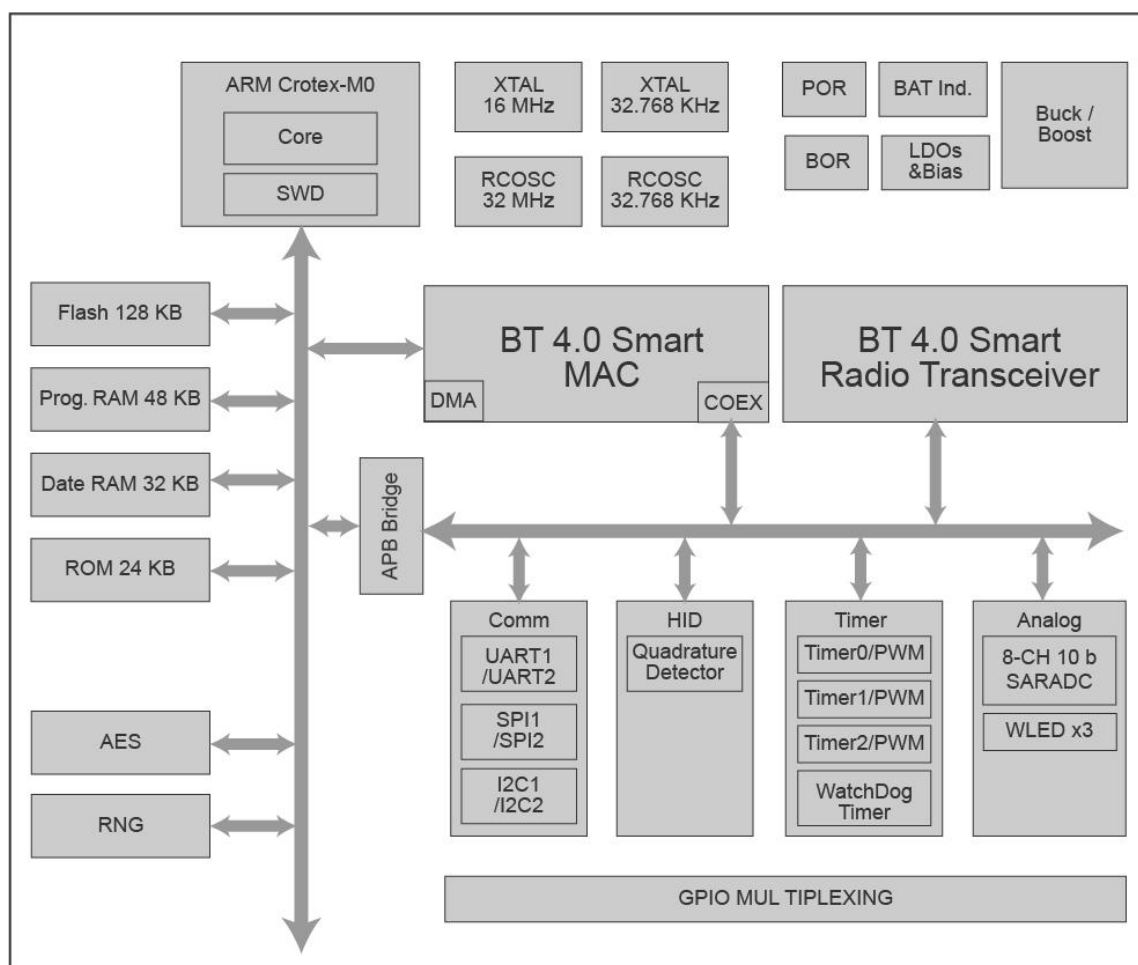


Figure 1. Functional Block Diagram of PAR2801QN-GHVC Chip

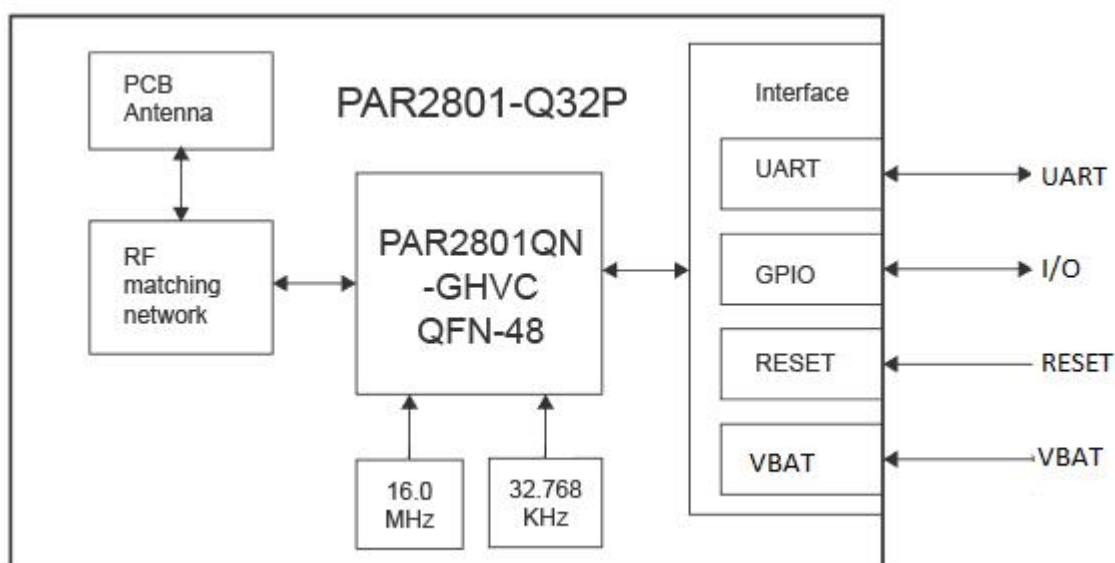


Figure 2. Block Diagram of PAR2801-Q32P

2 Pin Configuration and Functions

2.1 Module Pin Diagram with Parts Placement

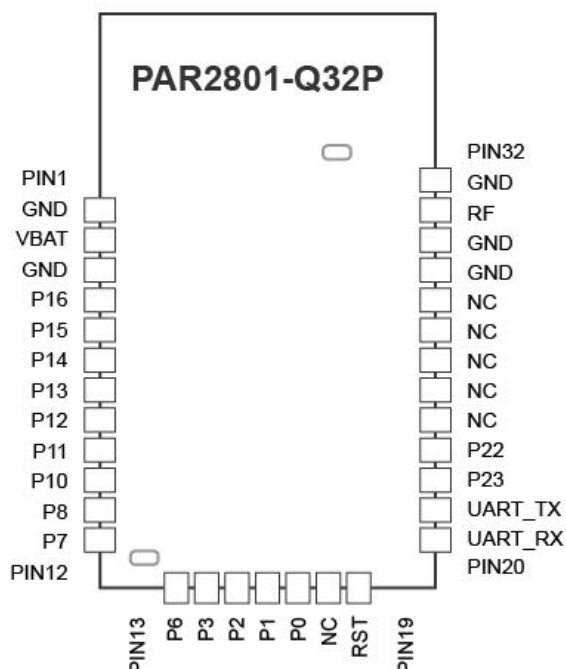


Figure 3. Pin Diagram of PAR2801-Q32P

2.2 Pinout Description

2.2.1 Pinout Description

Pin	Name	Pin Type	Description
1	GND	Power	Ground
2	VBAT	Power	Input power pin, connecting to a battery or an external power source. Recommended to add decoupling capacitor, 10 μ F. Keep PCB trace as short and wide as possible.
3	GND	Power	Ground
4	GPIO16	BiDir	GPIO, MouseKey_B5, PWM0, or LED0 I2C: Data IO, I2C_SDA1
5	GPIO15	BiDir	GPIO, MouseKey_B4, PWM1, or LED1 I2C: Clock output, I2C_SCL1
6	GPIO14	BiDir	GPIO, MouseKey_CPI, PWM2, or LED2
7	GPIO13	BiDir	GPIO, MouseKey_Middle
8	GPIO12	BiDir	GPIO, MouseKey_Right
9	GPIO11	BiDir	GPIO, MouseKey_Left
10	GPIO10	BiDir	GPIO, Motion_Wake_Up as motion detect for external sensor, Active

			_Low
11	GPIO8	BiDir	GPIO SPI4W: Master, Chip Select, SPI_CSN SPI3W: Master, Chip Select, SPI_CSN
12	GPIO7	BiDir	GPIO SPI4W: Master, Data_input, SP_DI SPI3W: Master, Data_IO, SPI_DIO I2C: Data_IO, I2C_SDA0
13	GPIO6	BiDir	GPIO SPI4W: Master, Clock output, SPI_CLK SPI3W: Master, Clock output, SPI_CLK I2C: Clock output, I2C_SCL0
14	GPIO3	BiDir	GPIO SPI4W: Master, Data input, SPI_DI_1 UART: UART_RTS0
15	GPIO2	BiDir	GPIO, PWM0, or LED0 SPI4W: Master, Clock output, SPI_CLK_1 UART: UART_CTS0
16	GPIO1	BiDir	GPIO, PWM1, or LED1 Analog Input_1 I2C: Data IO, I2C_SDA1 UART: UART_TXD1
17	GPIO0	BiDir	GPIO, PWM2, or LED2 Analog Input_0 I2C: Clock output, I2C_SCL0 UART: UART_RXD0
18	NC		
19	RST	In	Active low signal at least 10 ms for HW reset. The module has add a RC POR circuit (R=100 k, C=100 nF) connected to VDDIO power domain.
20	GPIO26	BiDir	GPIO, PWM0, or LED0 I2C: Clockoutput, as I2C_SCL0, UART: UART_RXD0
21	GPIO27	BiDir	GPIO, PWM2, or LED2 I2C: Data IO, as I2C_SDA0 UART: UART_TXD0
22	GPIO23	BiDir	GPIO, or Key_Z2 I2C: Data IO, as I2C_SDA1 UART: UART_TXD1
23	GPIO22	BiDir	GPIO, or Key_Z1 I2C: Clock output, I2C_SCL1 UART: UART_RXD1
24	NC		
25	NC		

26	NC		
27	NC		
28	NC		
29	GND	Power	Ground
30	GND	Power	Ground
31	RF	BiDir	2.4 GHz transceiver RF port. Default connected to PCB antenna in the module.
32	GND	Power	Ground

2.2.2 IO Multiplexing Modes

GPIO#	0	1	2	3	4	5
GPIO0	GPIO0	Analog Input0		I2C_SCL1	UART_RXD1	PWM2/LED2
GPIO1	GPIO1	Analog Input1		I2C_SDA1	UART_TXD1	PWM1/LED1
GPIO2	GPIO2	M_SPICK_1			UART_CST0	PWM0/LED0
GPIO3	GPIO3	M_SPIDI_1			UART_RTS0	
GPIO6	GPIO6	M_SPICK_0	M_SPICK_0	I2C_SCL0		
GPIO7	GPIO7	M_SPIDI_0	M_SPI_IO_0	I2C_SDA0		
GPIO8	GPIO8	M_SPICSN_0	M_SPICSN_0			
GPIO10	GPIO10	MOTION_Wake_UP				
GPIO11	GPIO11	MouseKey(BL)				
GPIO12	GPIO12	MouseKey(BR)				
GPIO13	GPIO13	MouseKey(BM)				
GPIO14	GPIO14	MouseKey(CPI)				PWM2/LED2
GPIO15	GPIO15	MouseKey(B4)		I2C_SCL1		PWM1/LED1
GPIO16	GPIO16	MouseKey(B5)		I2C_SDA1		PWM0/LED0
GPIO22	GPIO22	MouseKey(Z1)		I2C_SCL1	UART_RXD1	
GPIO23	GPIO23	MouseKey(Z2)		I2C_SDA1	UART_TXD1	
GPIO26	GPIO26			I2C_SCL0	UART_RXD0	PWM0/LED0
GPIO27	GPIO27			I2C_SDA0	UART_TXD0	PWM2/LED2

3 Specification

3.1 Absolute Maximum Rating

Parameter	Symbol	Min.	Max.	Unit	Note
V _{BAT} Voltage	V _{BAT3V}	-0.4	V _{BAT} + 0.3	V	
ESD	ESD _{HBM}		2	kV	Class 2 on all pins, as per human body model. JESD22-A114E with 15 sec internal.

3.2 Recommended Operating Conditions

Parameter	Symbol	Min.	Typ.	Max.	V	Note
Supply Voltage	V _{BAT3V}	1.9	3.0	3.6	V	Including ripples.
Storage Temperature	T _S	-40	-	85	°C	
Operating Temperature	T _J	-20	-	70	°C	

3.3 RF Characteristics

3.3.1 Transmitter Specification

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Frequency Range	FR _{TX}		2402	-	2480	MHz
Max. Output Power	P _{O, MAX}		-		4	dBm
Default Output Power	P _{O, DEF}			0		dBm
Output Power Adjust Range	P _{O, ADJ}		-30		4	dBm
Output Power Variation	P _{O, VAR}	All channels TX power variation		2.0		dBm
TX 20 dB Bandwidth	BW _{20dB}				1150	kHz
1 st Adjacent Channel Power	P _{AJC1}				-20	dBc
2 nd Adjacent Channel Power	P _{AJC2}				-40	dBc
Delta F1 Frequency Deviation	f _{1AVG}		225		275	kHz
Delta F2 Frequency Deviation	f _{2AVG}		185			kHz
AVG Delta F2/Delta F1	f _{AVG}	Δf _{2AVG} /Δf _{1AVG}	0.8			
Frequency Offset	F _{OFFSET}		-150		150	kHz
Carrier Frequency Drift	CF _{DRIFT}				50	kHz
Carrier Frequency Drift rate	CF _{DRIFT_Rate}				20	kHz/50 μs
2 nd Harmonics Power Level	Har _{2nd}	@P _{out} = 0 dBm			-40	dBm

3 rd Harmonics Power Level	Har _{3rd}	@Pout = 0 dBm			-45	dBm
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Notes:

Electrical characteristics are measured under BLE specification and recommended operating conditions.

3.3.2 Receiver Specification

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Frequency Range	FR _{TX}		2402	-	2480	MHz
Maximum Input Power	RX _{MAX}	With PER < 30.8%		0		dBm
Ideal Signal Sensitivity	SEN _{IDEAL}			-93		dBm
Dirty Signal Sensitivity	SEN _{DIRTY}			-90		dBm
C/I and Selectivity						
C/I Co-Channel	C/I _{CO}			9		dB
C/I Adjacent +1 MHz	C/I _{1M}			-1		dB
C/I Adjacent +2 MHz	C/I _{2M}			-35		dB
C/I Adjacent ≥ +3 MHz	C/I _{3M}		-40	-48		dB
C/I Image Channel	C/I _{IMG}			-25		dB
C/I Image + 1 M Channel	C/I _{IMG+1M}			-35		dB
Inter-Modulation Performance						
IMD Performance	IMD	3 rd , 4 th and 5 th offset channel	-24			dBm
Blocking Performance						
Blocking 30 MHz ~ 2000 MHz	P _{BLK_30~2000MHz}		-10			dBm
Blocking 2003 MHz ~ 2399 MHz	P _{BLK_2003~2399MHz}		-30			dBm
Blocking 2484 MHz ~ 2497 MHz	P _{BLK_2484~2497MHz}		-30			dBm
Blocking 3000 MHz ~ 12.75 GHz	P _{BLK_3~12.75GHz}		-10			dBm

Notes:

Electrical characteristics are measured under BLE specification and recommended operating conditions.

3.4 Power Consumption Summary

Parameters	Condition	Min.	Typ.	Max.	Unit
Supply Current @DTM-TX RF	@V _{BAT3V} = 3 V		10.0		mA
Supply Current @ DTM-RX	@V _{BAT3V} = 3 V		13.5		mA

4 Application, Implementation, and Layout

4.1 Application Diagram

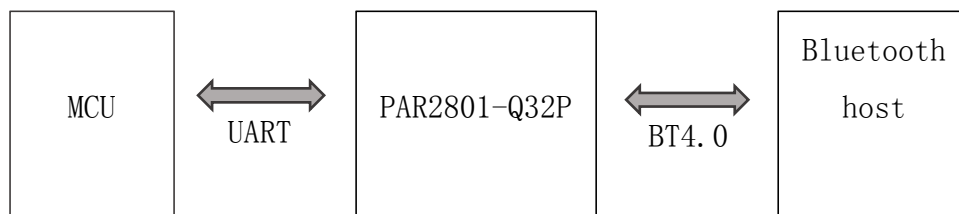


Figure 4. Bluetooth Transmission Application

4.2 Typical Application Circuit

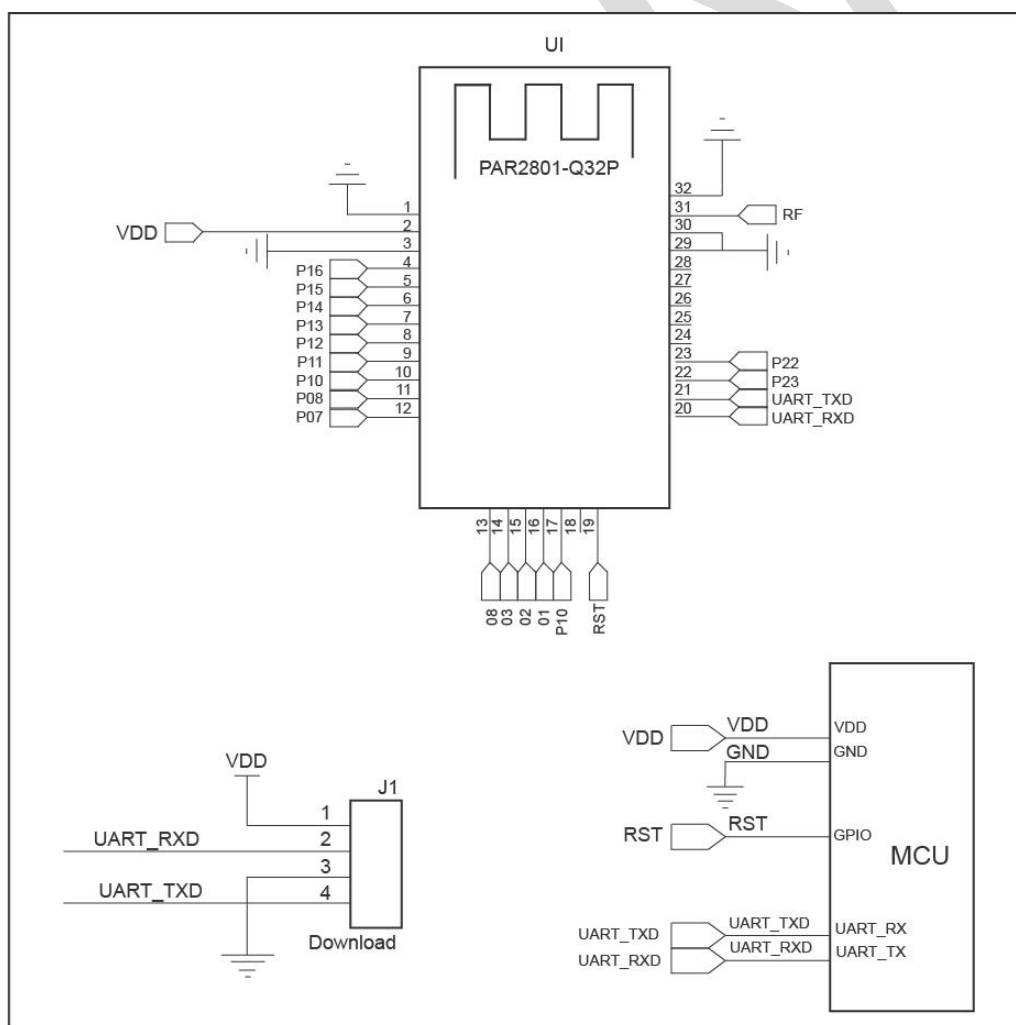


Figure 5. Typical Application Circuit

Note:

VDD: 1.9 V ~ 3.6 V; Recommended VDD: 3.0 V

4.3 Layout Guideline

1. It is recommended to place the module at the edge of the main board. The PCB antenna should be oriented towards the outside of the board and away from interference sources such as DC-DC.
2. The PCB antenna area in the main board should be free of all layers of copper, and there should be no wiring.

5 Mechanical and Package

5.1 Recommended PCB Footprint

L: 12.20 mm \pm 0.13 mm; W: 21.00 mm \pm 0.13 mm; H: 1.8 mm \pm 0.2 mm

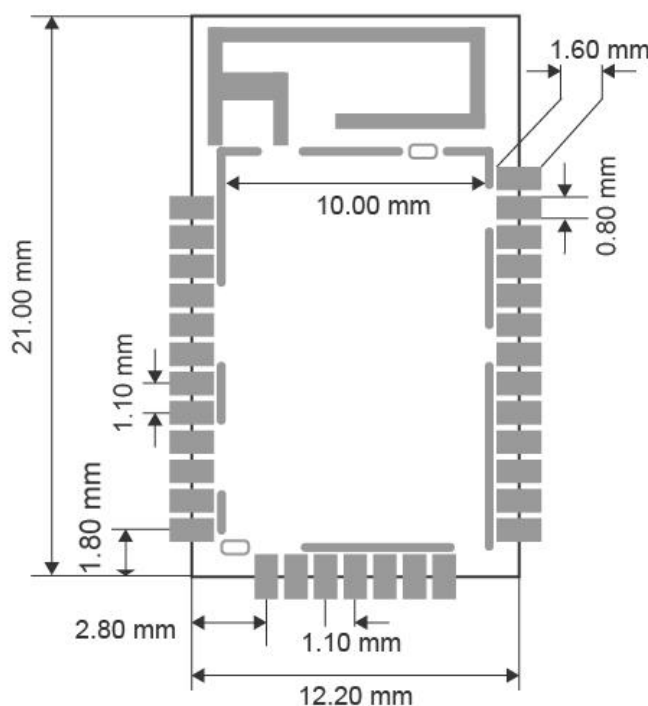


Figure 6. Recommended PCB Footprint of PAR2801-Q32P

5.2 Package Information

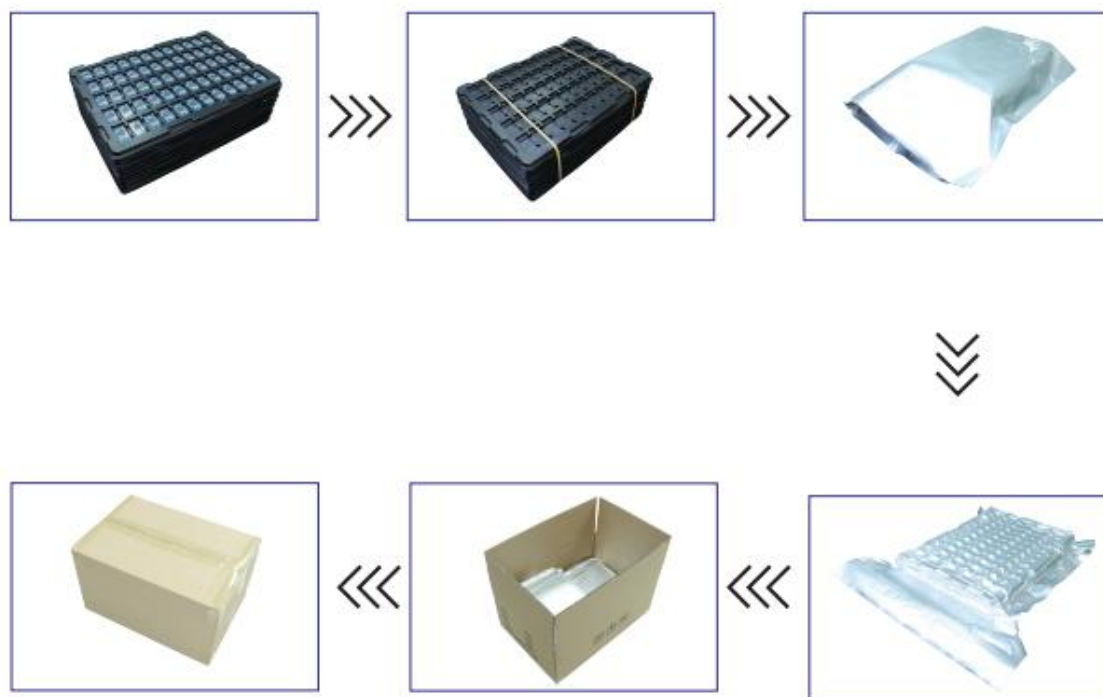


Figure 7. Brief Packaging Process of PAR28011-Q32P Modules

6 Thermal Reflow

Referred to IPC/JEDEC standard.

Peak temperature: <250 °C

Number of times: ≤2

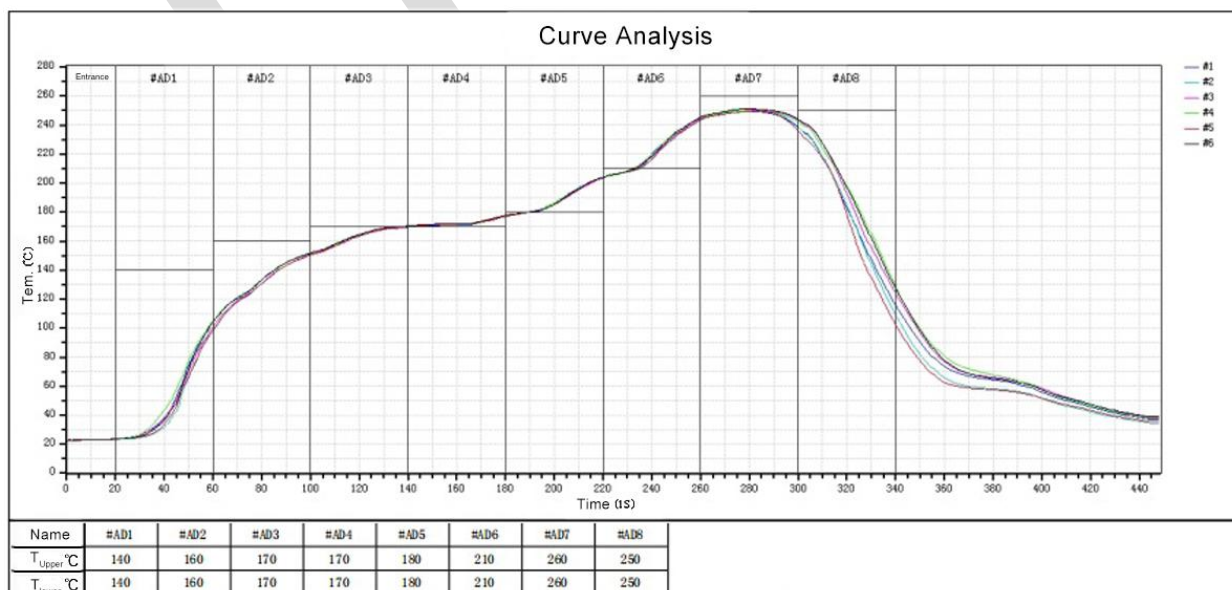


Figure 8. Recommended Reflow for Lead Free Solder

Note: The module is recommended not to go through reflow oven twice.

7 Revision History

Version	Change Content	Reviser	Date
V1.0	The initial version	Lei Wang	2018.11.02
V1.1	Updated Bluetooth version	Lei Wang	2019.04.26
V1.2	Modified English version	Lei Wang	2019.08.08
V1.3	Updated the block diagram and application diagram of the module	Lei Wang	2019.11.11
V2.0	Changed the Storage Temperature	Lei Wang	2020.06.01